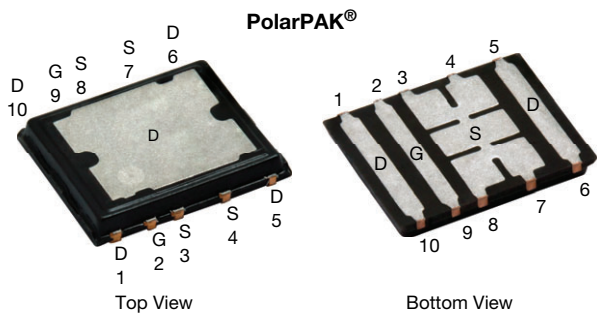
N-Channel 20 V (D-S) MOSFET



Top View Bottom View

Top surface is connected to pins 1, 5, 6, and 10

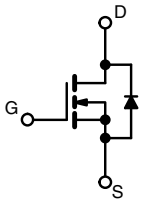
FEATURES

- TrenchFET® power MOSFET
- Ultra low thermal resistance using top-exposed PolarPAK® package for double-sided cooling
- Leadframe-based encapsulated package
  - Die not exposed
  - Same layout regardless of die size
- Low Q_{gd}/Q_{gs} ratio helps prevent shoot-through
- 100 % R_g and UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

RoHS COMPLIANT
HALOGEN FREE Available

APPLICATIONS

- VRM
- DC/DC conversion
- Synchronous rectification



N-Channel MOSFET

PRODUCT SUMMARY	
V_{DS} (V)	20
$R_{DS(on)}$ max. (Ω) at V_{GS} = 10 V	0.0034
$R_{DS(on)}$ max. (Ω) at V_{GS} = 4.5 V	0.0055
Q_g typ. (nC)	24
I_D (A) [a] (package limit)	50
I_D (A) [a] (silicon limit)	138
Configuration	Single

ORDERING INFORMATION	
Package	PolarPAK
Lead (Pb)-free	SiE822DF-T1-E3
Lead (Pb)-free and halogen-free	SiE822DF-T1-GE3

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNIT
Drain-source voltage		V_{DS}	20	V
Gate-source voltage		V_{GS}	± 20	
Continuous drain current (T_J = 150 °C)	T_C = 25 °C	I_D	50 [a] (package limit)	A
			138 (silicon limit)	
	T_C = 70 °C		50 [a]	
	T_A = 25 °C		31 [b, c]	
	T_A = 70 °C		24.8 [b, c]	
Pulsed drain current		I_{DM}	80	
Continuous source-drain diode current	T_C = 25 °C	I_S	50 [a]	
	T_A = 25 °C		4.3 [b, c]	
Single pulse avalanche current	L = 0.1 mH	I_{AS}	30	
Avalanche energy		E_{AS}	45	mJ
Maximum power dissipation	T_C = 25 °C	P_D	104	W
	T_C = 70 °C		66	
	T_A = 25 °C		5.2 [b, c]	
	T_A = 70 °C		3.3 [b, c]	
Operating junction and storage temperature range		T_J, T_{stg}	-55 to +150	°C
Soldering recommendations (peak temperature) [d, e]			260	

Notes

a. Package limited is 50 A
b. Surface mounted on 1" x 1" FR4 board
c. t = 10 s
d. See solder profile (www.vishay.com/doc?73257). The PolarPAK is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components

For technical questions, contact: pmostechsupport@vishay.com

THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

THERMAL RESISTANCE RATINGS

PARAMETER		SYMBOL	TYPICAL	MAXIMUM	UNIT
Maximum junction-to-ambient [a, b]	t ≤ 10 s	R_{thJA}	20	24	°C/W
Maximum junction-to-case (drain top) [a]	Steady state	R_{thJC} (drain)	1	1.2	
Maximum junction-to-case (source) [a, c]		R_{thJC} (source)	2.8	3.4	

Notes
a. Surface mounted on 1" x 1" FR4 board
b. Maximum under steady state conditions is 68 °C/W
c. Measured at source pin (on the side of the package)

SPECIFICATIONS (T_J = 25 °C, unless otherwise noted)

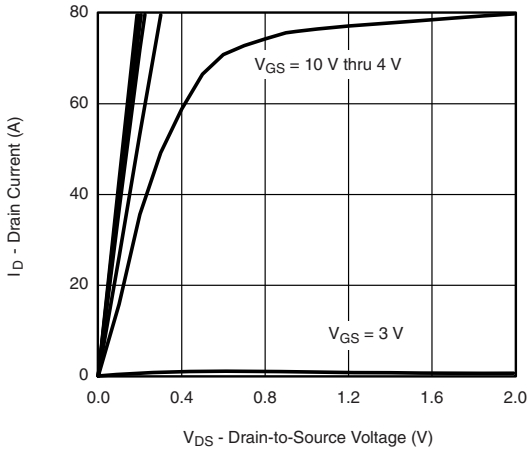
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static						
Drain-source breakdown voltage	V_{DS}	V_{GS} = 0 V, I_D = 250 µA	20	-	-	V
V_{DS} temperature coefficient	$\Delta V_{DS}/T_J$	I_D = 250 µA	-	24.1	-	mV/°C
$V_{GS(th)}$ temperature coefficient	$\Delta V_{GS(th)}/T_J$		-	-7.1	-	
Gate-source threshold voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 250 µA	1.5	2.3	3.0	V
Gate-source leakage	I_{GSS}	V_{DS} = 0 V, V_{GS} = ± 20 V	-	-	± 100	nA
Zero gate voltage drain current	I_{DSS}	V_{DS} = 20 V, V_{GS} = 0 V	-	-	1	µA
		V_{DS} = 20 V, V_{GS} = 0 V, T_J = 55 °C	-	-	10	
On-state drain current [a]	$I_{D(on)}$	V_{DS} ≥ 5 V, V_{GS} = 10 V	25	-	-	A
Drain-source on-state resistance [a]	$R_{DS(on)}$	V_{GS} = 10 V, I_D = 18.3 A	-	0.0028	0.0034	Ω
		V_{GS} = 4.5 V, I_D = 14.5 A	-	0.0045	0.0055	
Forward transconductance [a]	g_{fs}	V_{DS} = 15 V, I_D = 18.3 A	-	90	-	S
Dynamic [b]						
Input capacitance	C_{iss}	V_{DS} = 10 V, V_{GS} = 0 V, f = 1 MHz	-	4200	-	pF
Output capacitance	C_{oss}		-	1000	-	
Reverse transfer capacitance	C_{rss}		-	320	-	
Total gate charge	Q_g	V_{DS} = 10 V, V_{GS} = 10 V, I_D = 20 A	-	52	78	nC
		V_{DS} = 10 V, V_{GS} = 4.5 V, I_D = 20 A	-	24	36	
Gate-source charge	Q_{gs}		-	13	-	
Gate-drain charge	Q_{gd}		-	5	-	
Gate resistance	R_g	f = 1 MHz	-	1	1.5	Ω
Turn-on delay time	$t_{d(on)}$	V_{DD} = 10 V, R_L = 1 Ω, I_D ≅ 10 A, V_{GEN} = 4.5 V, R_g = 1 Ω	-	50	75	ns
Rise time	t_r		-	220	330	
Turn-off delay time	$t_{d(off)}$		-	35	55	
Fall time	t_f		-	20	30	
Turn-on delay time	$t_{d(on)}$	V_{DD} = 20 V, R_L = 1 Ω, I_D ≅ 10 A, V_{GEN} = 10 V, R_g = 1 Ω	-	15	25	
Rise time	t_r		-	25	40	
Turn-off delay time	$t_{d(off)}$		-	35	55	
Fall time	t_f		-	10	15	
Drain-Source Body Diode Characteristics						
Continuous source-drain diode current	I_S	T_C = 25 °C	-	-	50	A
Pulse diode forward current [a]	I_{SM}		-	-	80	
Body diode voltage	V_{SD}	I_S = 10 A	-	0.8	1.2	V
Body diode reverse recovery time	t_{rr}	I_F = 10 A, di/dt = 100 A/µs, T_J = 25 °C	-	40	60	ns
Body diode reverse recovery charge	Q_{rr}		-	36	60	nC
Reverse recovery fall time	t_a		-	19	-	ns
Reverse recovery rise time	t_b		-	21	-	

Notes
a. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %
b. Guaranteed by design, not subject to production testing

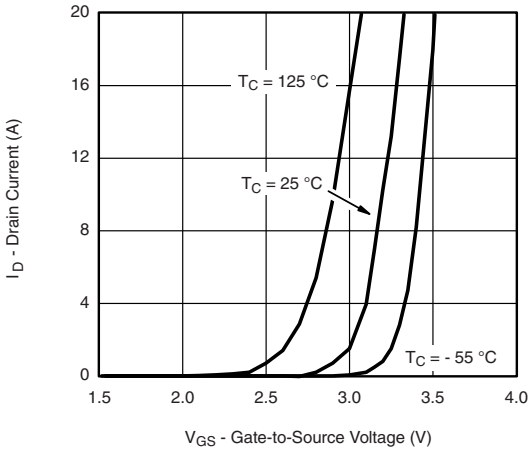
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

For technical questions, contact: pmostechsupport@vishay.com
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

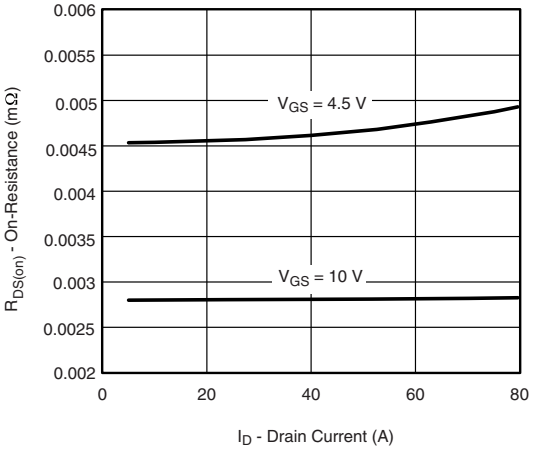
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



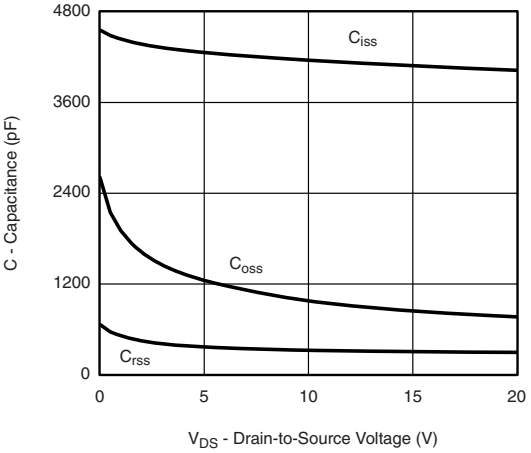
Output Characteristics



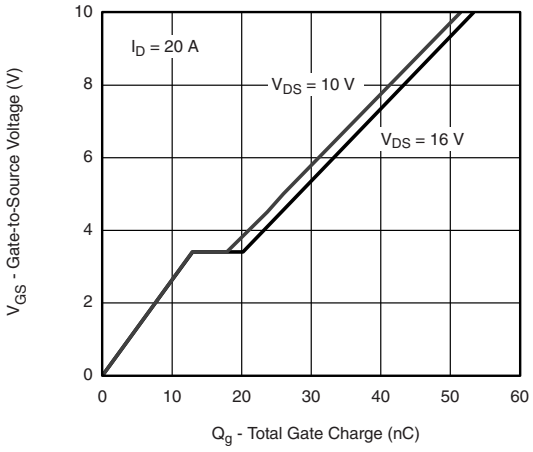
Transfer Characteristics



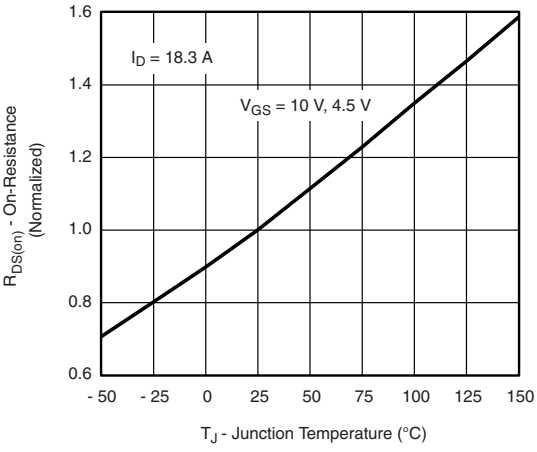
On-Resistance vs. Drain Current



Capacitance



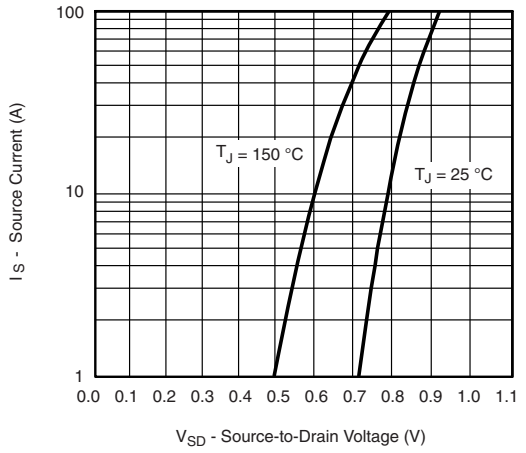
Gate Charge



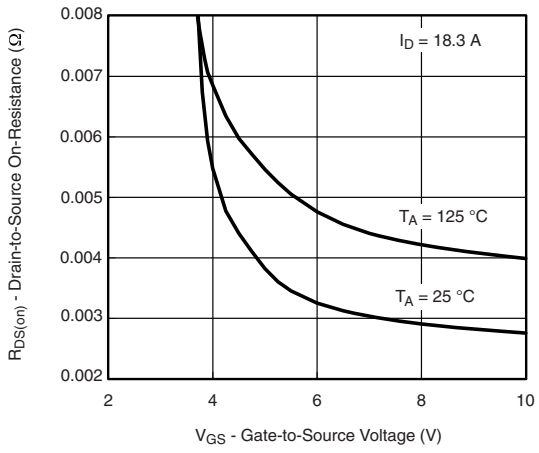
On-Resistance vs. Junction Temperature

For technical questions, contact: pmostechsupport@vishay.com
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

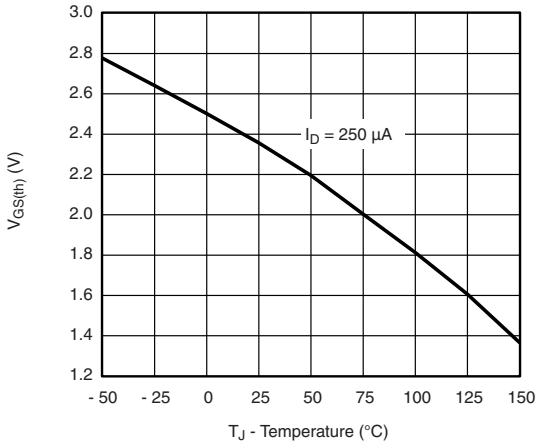
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



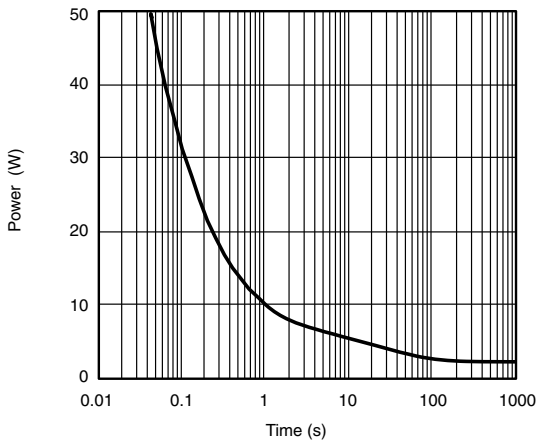
Source-Drain Diode Forward Voltage



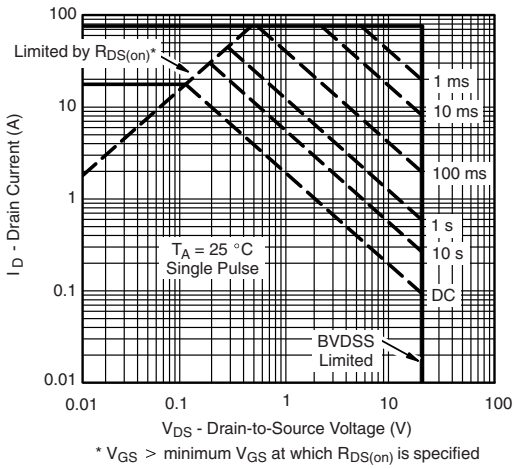
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



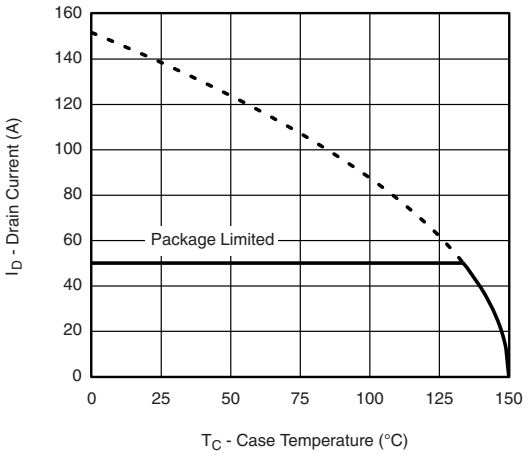
Single Pulse Power, Junction-to-Ambient



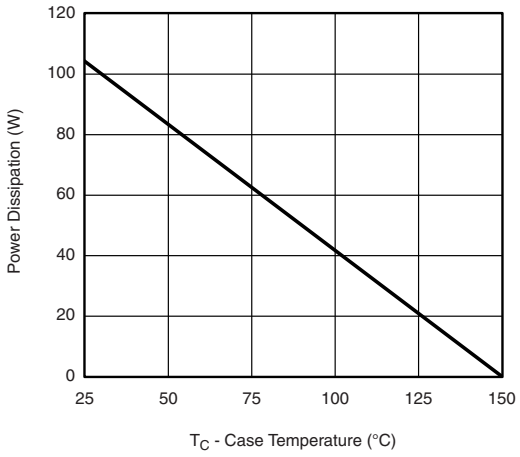
Safe Operating Area, Junction-to-Ambient

For technical questions, contact: pmostechsupport@vishay.com
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Current Derating [a]



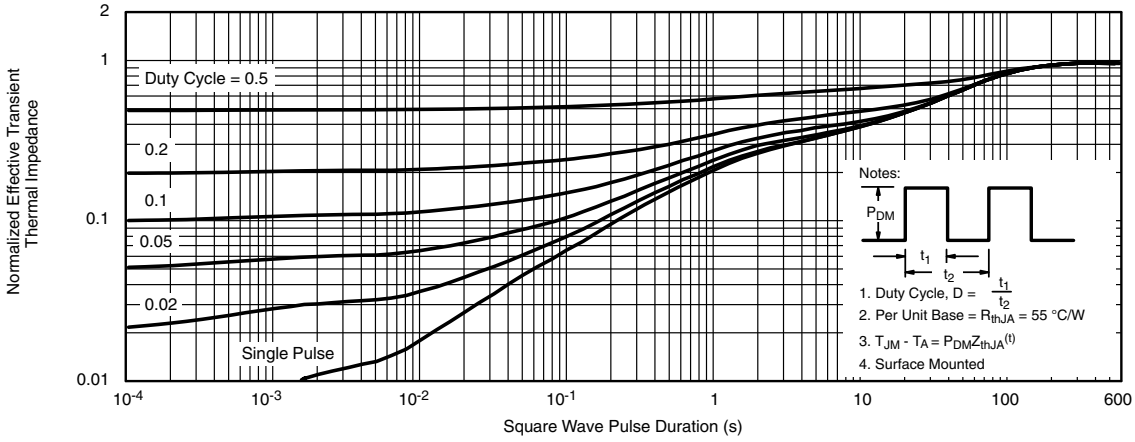
Power Derating, Junction-to-Case

Note

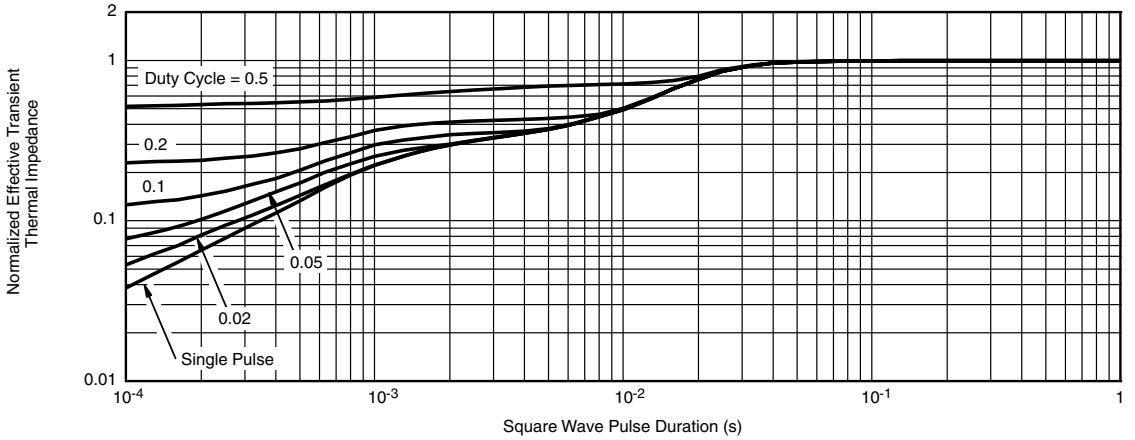
a. The power dissipation P_D is based on T_J max. = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit

For technical questions, contact: pmostechsupport@vishay.com
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

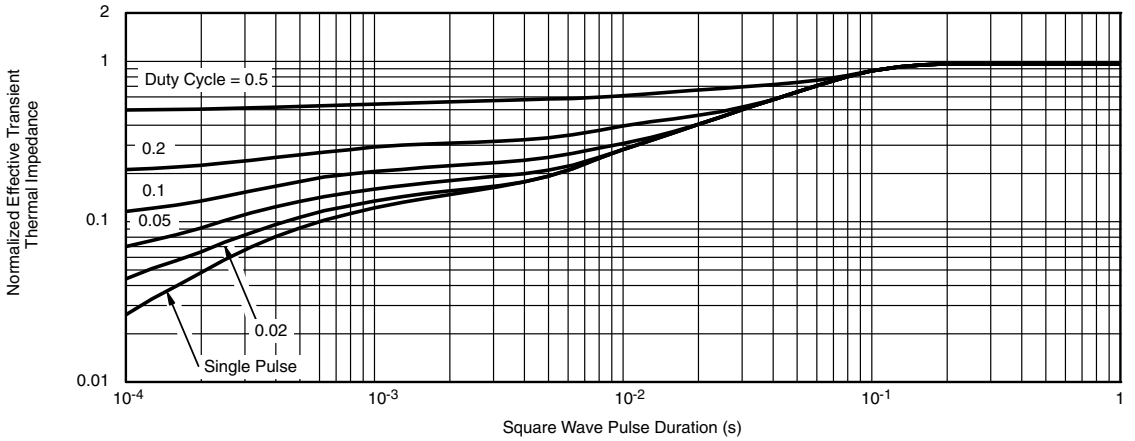
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case (Drain Top)



Normalized Thermal Transient Impedance, Junction-to-Source

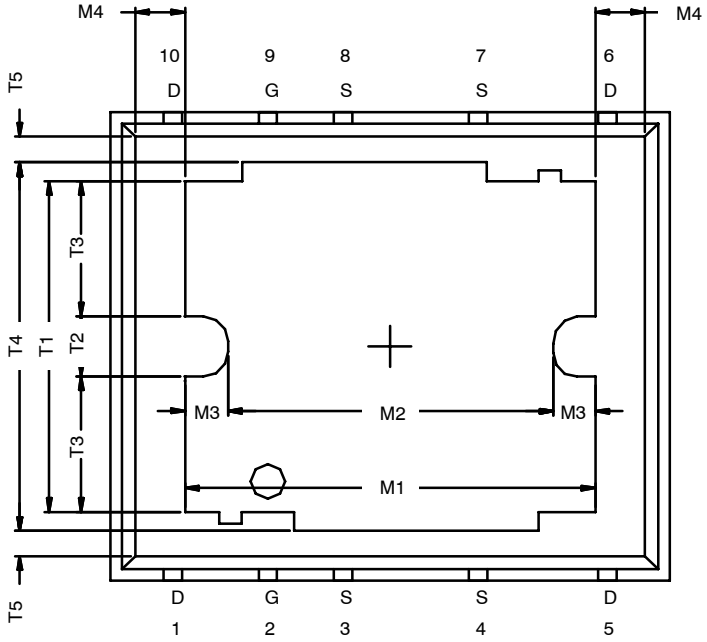
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?74451.

For technical questions, contact: pmostechsupport@vishay.com

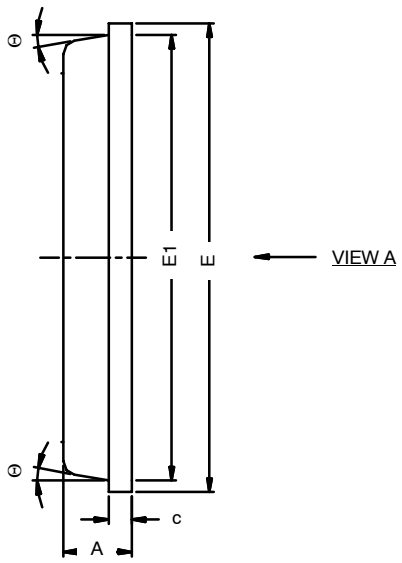
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

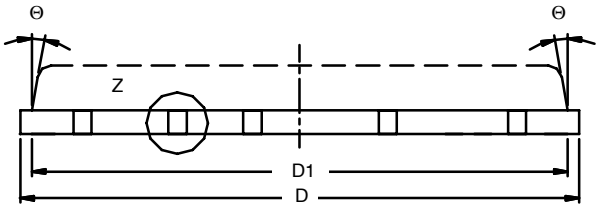
PolarPAK™ (Option S)

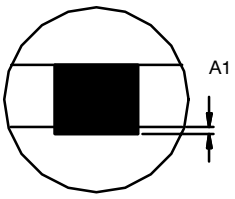
Product datasheet/information page contain links to applicable package drawing.



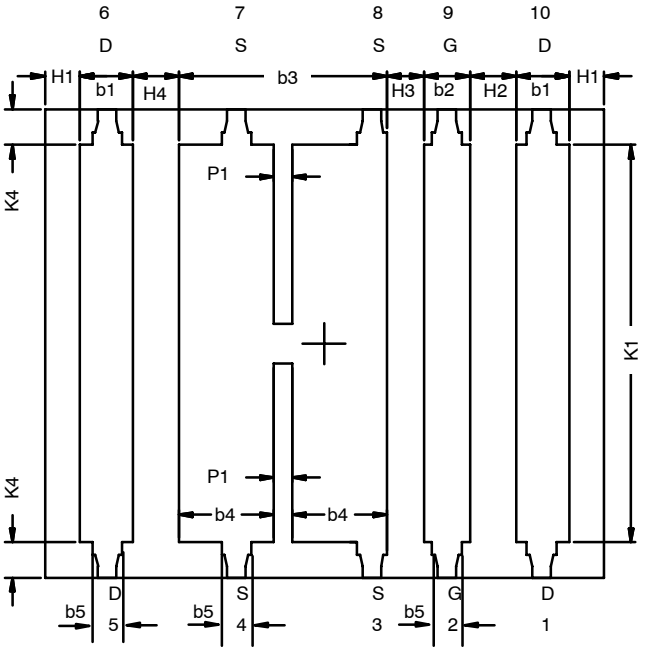
(Top View)







DETAIL Z



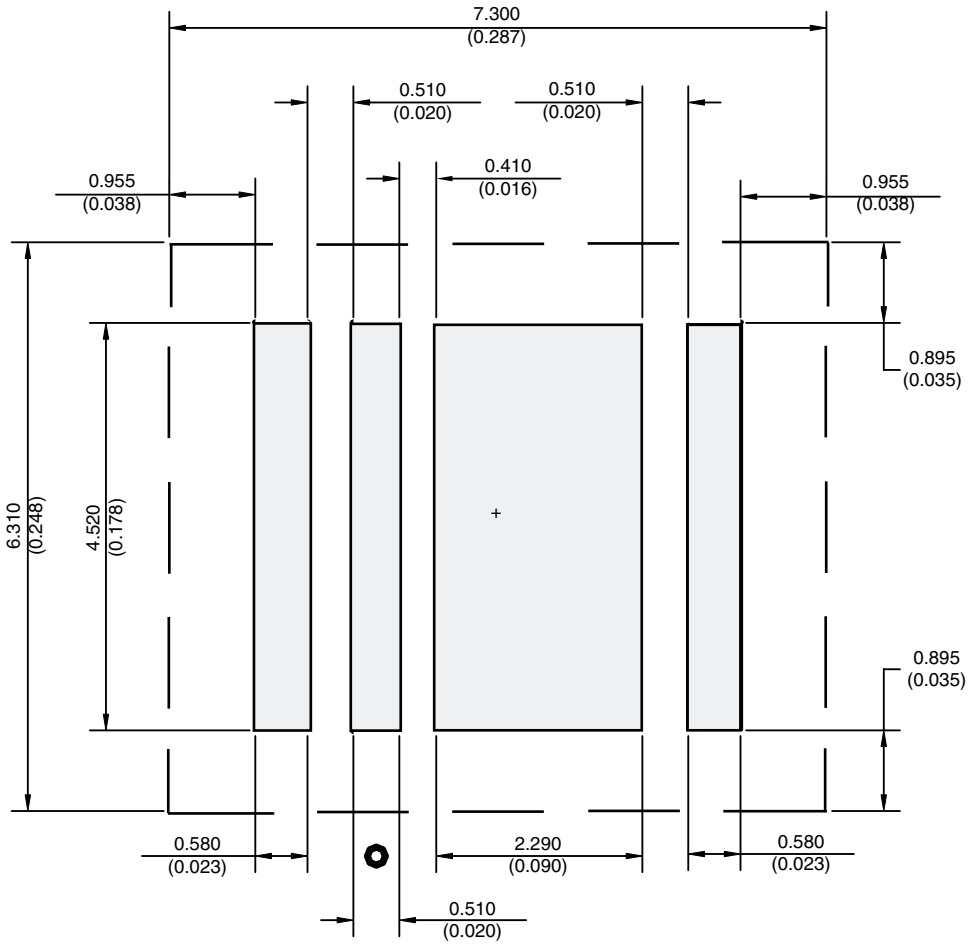
VIEW A

(Bottom View)

Dim	MILLIMETERS			INCHES		
	Min	Nom	Max	Min	Nom	Max
A	0.75	0.80	0.85	0.030	0.031	0.033
A1	0.00	–	0.05	0.000	–	0.002
b1	0.48	0.58	0.68	0.019	0.023	0.027
b2	0.41	0.51	0.61	0.016	0.020	0.024
b3	2.19	2.29	2.39	0.086	0.090	0.094
b4	0.89	1.04	1.19	0.035	0.041	0.047
b5	0.23	0.33	0.43	0.009	0.013	0.017
c	0.20	0.25	0.30	0.008	0.010	0.012
D	6.00	6.15	6.30	0.236	0.242	0.248
D1	5.74	5.89	6.04	0.226	0.232	0.238
E	5.01	5.16	5.31	0.197	0.203	0.209
E1	4.75	4.90	5.05	0.187	0.193	0.199
H1	0.23	–	–	0.009	–	–
H2	0.45	–	0.56	0.020	–	0.022
H3	0.31	0.41	0.51	0.012	0.016	0.020
H4	0.45	–	0.56	0.020	–	0.022
K1	4.22	4.37	4.52	0.166	0.172	0.178
K4	0.24	–	–	0.009	–	–
M1	4.30	4.50	4.70	0.169	0.177	0.185
M2	3.43	3.58	3.73	0.135	0.141	0.147
M3	0.22	–	–	0.009	–	–
M4	0.05	–	–	0.002	–	–
P1	0.15	0.20	0.25	0.006	0.008	0.010
T1	3.48	3.64	4.10	0.137	0.143	0.150
T2	0.56	0.76	0.95	0.22	0.030	0.037
T3	1.20	–	–	0.051	–	–
T4	3.90	–	–	0.154	–	–
T5	0	0.18	0.36	0.000	0.007	0.014
Θ	0°	10°	12°	0°	10°	12°
ECN: S–51049—Rev. B, 13-Jun-05 DWG: 5947						

Note: Millimeters govern over inches

RECOMMENDED MINIMUM PADS FOR PolarPAK® Option L and S



Recommended Minimum for PolarPAK Option L and S
Dimensions in mm/(Inches)
No External Traces within Broken Lines
Dot indicates Gate Pin (Part Marking)

Return to Index

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, “Vishay”), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

© 2024 VISHAY INTERTECHNOLOGY, INC. ALL RIGHTS RESERVED